

L Number	Hits	Search Text	DB	Time stamp
1	332	(\$6thiophene thiophene) and (TFT (thin adj film adj transistor semiconduct\$3 device)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:56
8	22	5853906.URPN.	USPAT	2002/09/19 17:36
9	18	5347144.URPN.	USPAT	2002/09/19 18:06
10	2157	gate near20 (Au gold)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:02
17	3518	source near20 (Au gold)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:55
24	1431	drain near20 (Au gold)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:55
31	57	"source/drain" near20 (Au gold)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:55
38	1155	((source near20 (Au gold)) and (drain near20 (Au gold))) or ("source/drain" near20 (Au gold))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:55
45	685	(gate near20 (Au gold)) and (((source near20 (Au gold)) and (drain near20 (Au gold))) or ("source/drain" near20 (Au gold)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:55
52	98	((gate near20 (Au gold)) and (((source near20 (Au gold)) and (drain near20 (Au gold))) or ("source/drain" near20 (Au gold)))) and (TFT (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:57
59	40784	substrate near20 (polycarbonate polyester polyimide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 18:59
66	95	(gate adj (insulat\$3 dielectric isolation)) near20 (polycarbonate polyester polyimide polyacrylate polymethylacrylate polystyrene polyvinylphenol)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:01
73	12	gate near20 (conductive adj (paste ink))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:03
80	162	source near20 (conductive adj (paste ink))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:03

87	13	drain near20 (conductive adj (paste ink))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:03
94	0	"source/drain" near20 (conductive adj (paste ink))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:03
101	6	(gate near20 (conductive adj (paste ink))) and (source near20 (conductive adj (paste ink))) and (drain near20 (conductive adj (paste ink)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:16
108	24	((gate near20 (Au gold)) and (((source near20 (Au gold)) and (drain near20 (Au gold))) or ("source/drain" near20 (Au gold)))) and (TFT (thin adj film adj transistor)) and (substrate near20 (polycarbonate polyester polyimide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:16
115	4	(((gate near20 (Au gold)) and (((source near20 (Au gold)) and (drain near20 (Au gold))) or ("source/drain" near20 (Au gold)))) and (TFT (thin adj film adj transistor)) and (substrate near20 (polycarbonate polyester polyimide))) and ((gate adj (insulat\$3 dielectric isolation)) near20 (polycarbonate polyester polyimide polyacrylate polymethylacrylate polystyrene polyvinylphenol))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/19 19:16